

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Docket No: Q76117

KIYOKU, Hiroyuki, et al.

This is a Divisional Application of
Appln. No.: 10/261,487

Confirmation No.: Unknown

Prior Group Art Unit: 2822

Filed: June 23, 2003

Prior Examiner: Stephen D. Meier

For: NITRIDE SEMICONDUCTOR GROWTH METHOD, NITRIDE SEMICONDUCTOR
SUBSTRATE, AND NITRIDE SEMICONDUCTOR DEVICE

PRELIMINARY AMENDMENT

MAIL STOP NON-FEE AMENDMENT

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

Prior to examination, please amend the above-identified application as follows:

IN THE SPECIFICATION:

Before the first line of the specification, please insert the following new paragraph:

This is a divisional of Application No. 10/261,487 filed October 2, 2002, now pending,
which is a divisional of Application No. 09/986,332 filed November 8, 2001, now pending,
which is a Continuation of application Serial No. 09/603,437 filed June 23, 2000, now
abandoned, which is a Division of application Serial No. 09/202,141 filed December 9, 1998,
now U.S. Patent 6,153,010, which is a 35 U.S.C. § 371 of PCT/JP98/01640 filed April 9, 1998.